

SPDT Low PIM up to 18 GHz

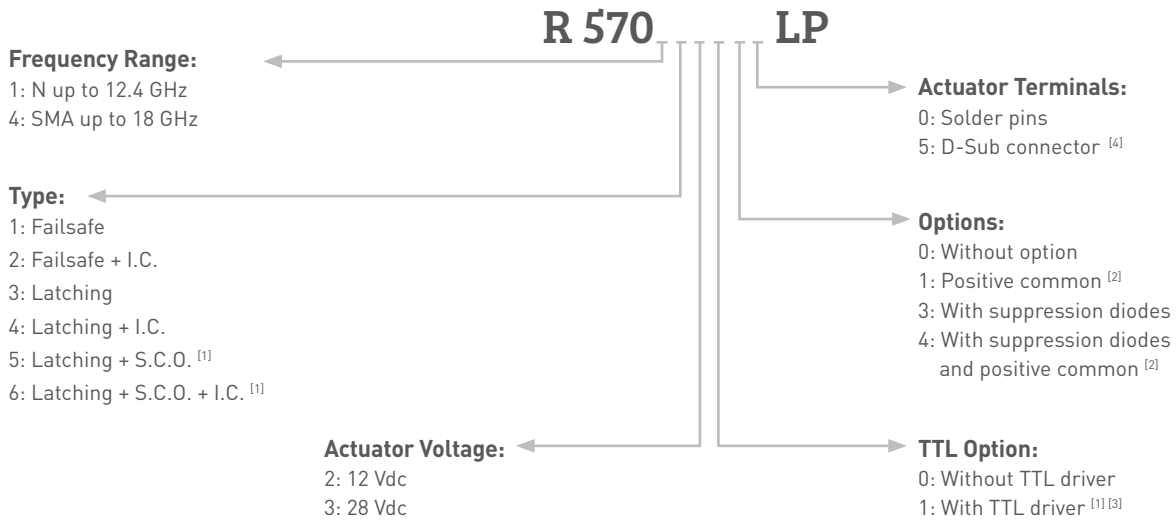


To meet growing market demands created by the deployment of 4G/LTE networks, Radiall has introduced a new range of Low PIM switches. RAMSES SPDT Low PIM switches are perfectly suited for RF test systems and test benches requiring excellent passive intermodulation performance up to 18 GHz; with a guarantee PIM performance of -160 dBc @ +43 dBm over a life span of 2 million switching cycles.

These products are specific to instrumentation and telecommunication applications.

Example of P/N:
R570413030LP is a SPDT Low PIM SMA 18 GHz, failsafe, 28 Vdc, with suppression diodes, solder pins.

PART NUMBER SELECTION



I.C.: Indicator contact - S.C.O.: Self Cut-Off

(1): Suppression diodes are already included in Self Cut-OFF & TTL option

(2): Positive common shall be specified only with type 3, 4, 5 & 6 because failsafe models can be used with both polarities

(3): Polarity is not relevant to application for switches with TTL driver

(4): Only available for N models

SPDT Low PIM up to 18 GHz

GENERAL SPECIFICATIONS

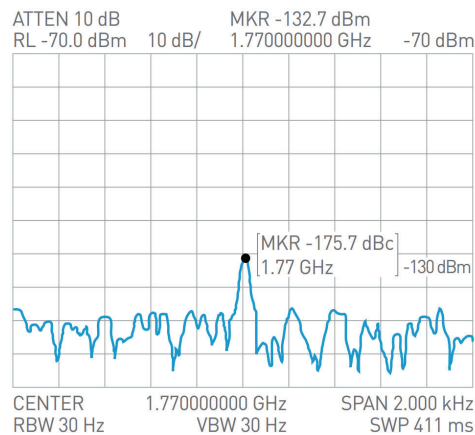
Operating mode		Failsafe		Latching		
Nominal operating voltage (across operating temperature)		Vdc	12 (10.2 to 13)	28 (24 to 30)	12 (10.2 to 13)	28 (24 to 30)
Coil resistance at 23°C (+/-10%)	SMA	Ω	47.5	275	58	350
	N		38	200	38	225
Operating current at 23°C	SMA	mA	250	102	210	80
	N		320	140	320	125
Average power		See Power Rating Chart on page 1-16				
TTL input	High Level		2.2 to 5.5 V (TTL Option) / 3.5 to 5.5 V (BCD Option)			
	Low Level		0 to 0.8 V (TTL Option) / 0 to 1.5 V (BCD Option)			
Indicator rating		1 Watt / 30 Volts / 100 mA				
Switching time		ms	15 ms			
Life (Min)		2 million cycles				
Connectors		SMA - N				
Actuator terminals		Solder pins or male 25 pin D-Sub connector				
Operating temperature range		-40°C to +85°C				
Storage temperature range		-55°C to +85°C				
Vibration (MIL STD 202, method 204D, cond.D)		10-2000 Hz - 20 g operating				
Shock (MIL STD 202, method 213B, cond.C)		100 g / 6 ms - ½ sine operating				

*Reset: supply voltage time 1 sec. max./duty cycle 10%

RF PERFORMANCE

Connectors	Number of positions	Frequency Range GHz	V.S.W.R. (max)	Insertion loss (max) dB	Isolation (min) dB	Impedance Ω	Third order intermodulation
SMA	4 and 6	DC - 18	DC - 3	1.20	0.20	80	-160 dBc @ +43 dBm [2 carriers 20 W]
			3 - 8	1.30	0.30	70	
			8 - 12.4	1.40	0.40	60	
			12.4 - 18	1.50	0.50	60	
N	DC - 12.4	DC - 3	1.20	0.20	80		
		3 - 8	1.35	0.35	70		
		8 - 12.4	1.50	0.50	60		

OUTSTANDING PIM PERFORMANCE



Passive Intermodulation

Tone 1	1810 MHz, approximately 43 dBm
Tone 2	1850 MHz, approximately 43 dBm
3rd order PIM	160 dBc at 1770 MHz

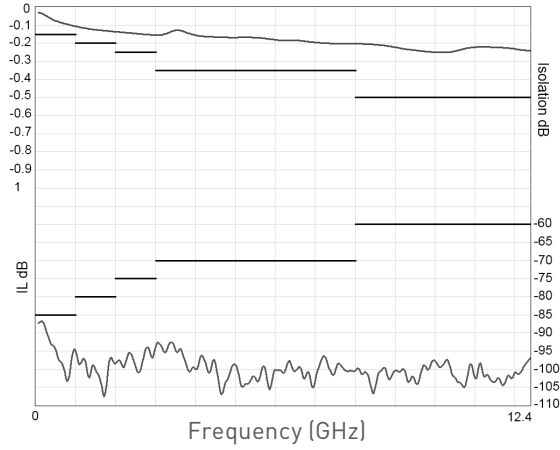
Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.

SPDT Low PIM up to 18 GHz

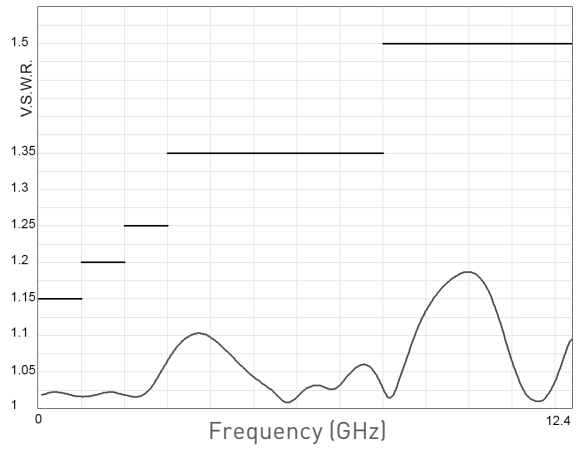
TYPICAL RF PERFORMANCE

Example: SPDT N up to 12.4 GHz

Insertion Loss and Isolation

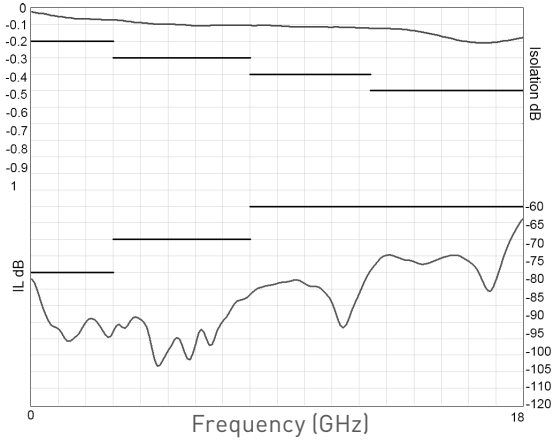


V.S.W.R.

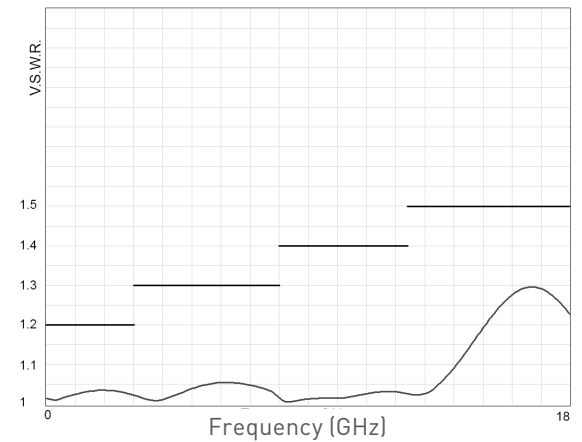


Example: SPDT SMA up to 18 GHz

Insertion Loss and Isolation



V.S.W.R.

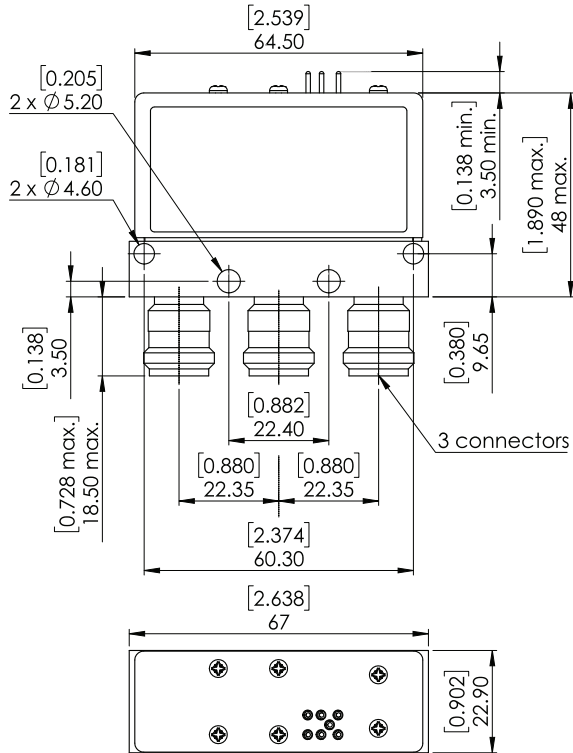


See electrical schematics from page 2-20 to 2-23.

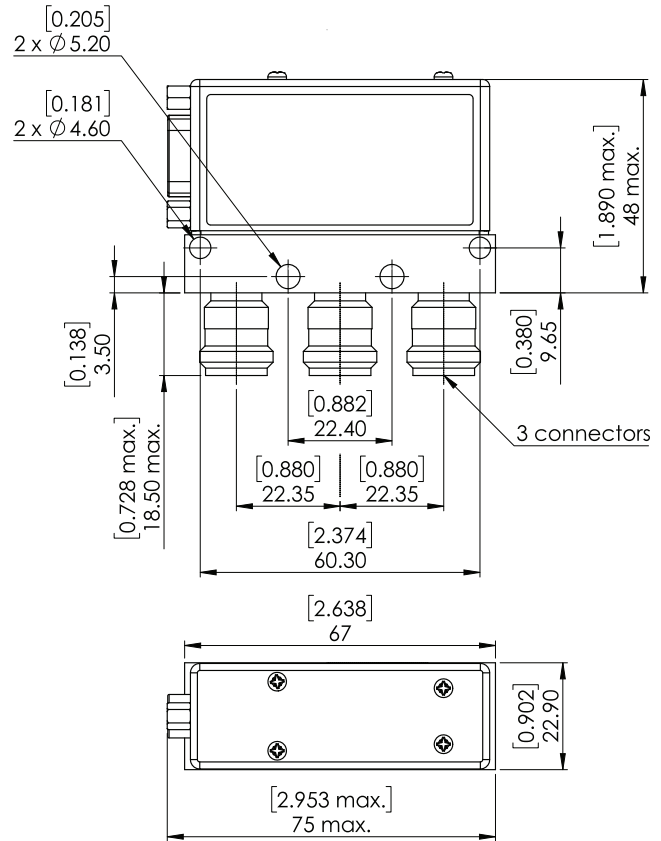
SPDT Low PIM up to 18 GHz

TYPICAL OUTLINE DRAWING

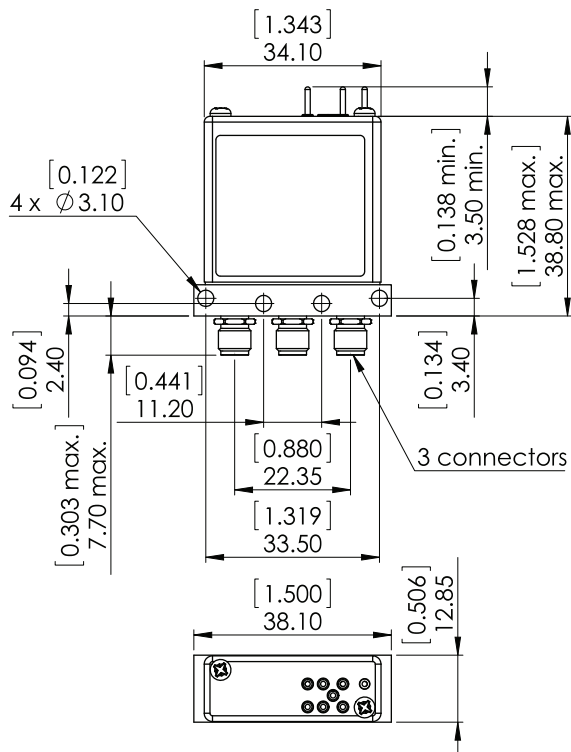
Example: SPDT N up to 12.4 GHz with pins



Example: SPDT N up to 12.4 GHz with D-sub



Example: SPDT SMA up to 18 GHz



All dimensions are in millimeters [inches].